TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED MESA TYPE

2SC5855

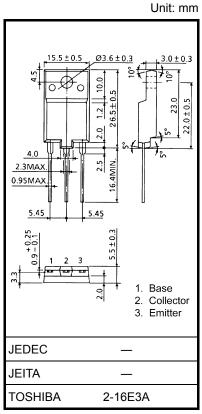
HORIZONTAL DEFLECTION OUTPUT FOR SUPER HIGH RESOLUTION DISPLAY, COLOR TV, DIGITAL TV HIGH SPEED SWITCHING APPLICATIONS

 High Voltage 	: VCBO = 1500 V
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- Low Saturation Voltage : V_{CE} (sat) = 3 V (max)
- High Speed : $t_{f(2)} = 0.1 \ \mu s \ (typ.)$

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Base Voltage		V _{CBO}	1500	V	
Collector-Emitter Voltage		V _{CEO}	700	V	
Emitter-Base Voltage		V _{EBO}	5	V	
Collector Current	DC	Ι _C	10	A	
	Pulse	I _{CP}	20		
Base Current		I _B	5	А	
Collector Power Dissipation		P _C	50	W	
Junction Temperature		Tj	150	°C	
Storage Temperature Range		T _{stg}	-55~150	°C	

ABSOLUTE MAXIMUM RATINGS (Tc = 25°C)



Weight: 5.5 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

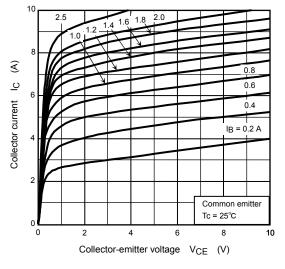
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

ELECTRICAL CHARACTERISTICS (Tc = 25°C)

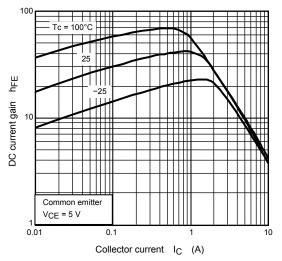
CHARACTER	RISTIC	SYMBOL	TEST CONDITION	Min	Тур.	Max	UNIT
Collector Cut-off Curre	ent	ICBO	V _{CB} = 1500 V, I _E = 0	_	_	1	mA
Emitter Cut-off Curren	t	I _{EBO}	V _{EB} = 5 V, I _C = 0	_	_	100	μA
Collector – Emitter Breakdown Voltage		V (BR) CEO	I _C = 10 mA, I _B = 0	700	_	_	V
DC Current Gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 A	28	_	60	
		h _{FE (2)}	V _{CE} = 5 V, I _C = 6 A	6.2	_	10	
		h _{FE (3)}	V _{CE} = 5 V, I _C = 8 A	4.3	_	6.7	
Collector-Emitter Saturation Voltage		V _{CE (sat)}	I _C = 8 A, I _B = 2 A	-	-	3	V
Base-Emitter Saturation Voltage		V _{BE (sat)}	I _C = 8 A, I _B = 2 A	_	1.0	1.4	V
Transition Frequency		f _T	V _{CE} = 10 V, I _C = 0.1 A	_	2	_	MHz
Collector Output Capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	120	_	pF
Switching Time	Storage Time	t _{stg(1)}	I _{CP} = 6 , I _{B1} (end) = 0.8 A f _H = 32 kHz	_	2.8	_	μs
	Fall Time	t _{f(1)}		_	0.2	_	
	Storage Time	t _{stg(2)}	I _{CP} = 5.5 A, I _{B1} (end) = 0.8 A f _H = 80 kHz	—	2.3	—	- µs
	Fall Time	t _{f(2)}		_	0.1	—	

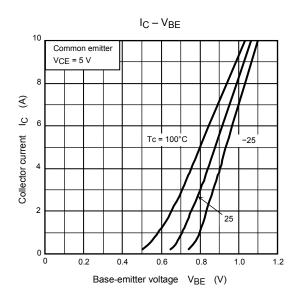
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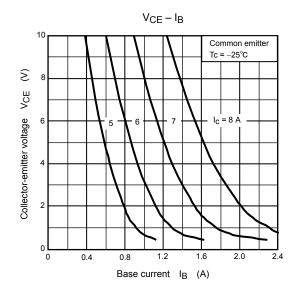


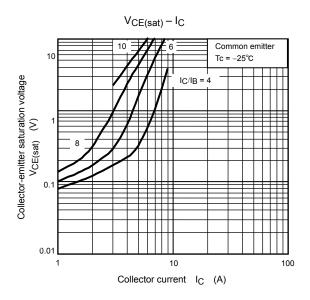


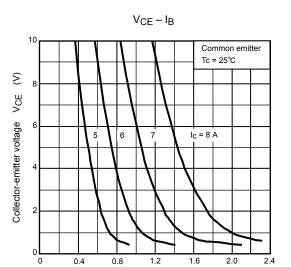




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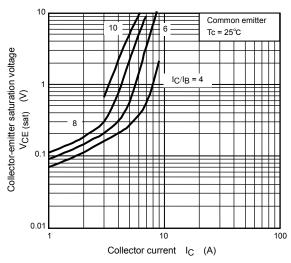


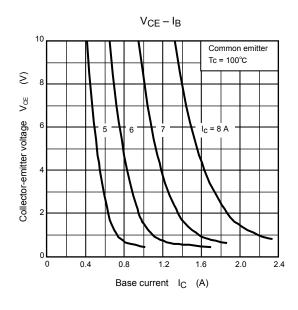


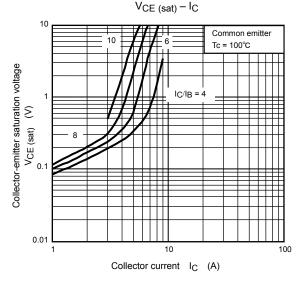


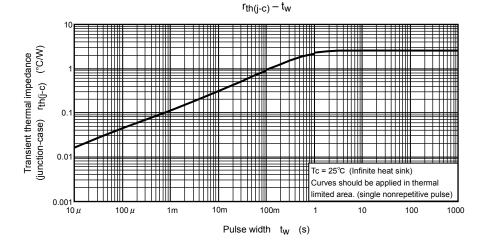
Base current I_B (A)

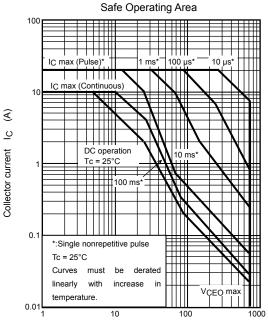


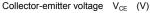


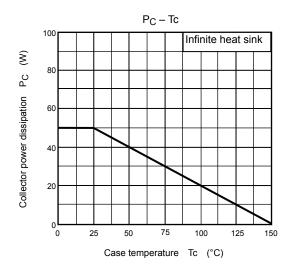




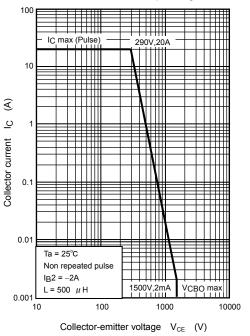








Reverse Bias - Safe Operating Area



RESTRICTIONS ON PRODUCT USE

20070701-EN

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